



CD4016M/CD4016C Quad Bilateral Switch

General Description

The CD4016M/CD4016C is a quad bilateral switch which utilizes P-channel and N-channel complementary MOS (CMOS) circuits to provide an extremely high "OFF" resistance and low "ON" resistance switch. The switch will pass signals in either direction and is extremely useful in digital switching.

Features

- Wide supply voltage range 3V to 15V
- High noise immunity 0.45 V_{CC} typ.
- Wide range of digital and analog levels ±7.5 V_{PEAK}
- Low "ON" resistance 300Ω typ.
V_{DD} = V_{SS} = 15V
- Matched switch characteristics ΔR_{ON} = 40Ω typ.
- High "ON/OFF" output voltage ratio 65 dB typ.
@ f_{IS} = 10 kHz
- R_L = 10k
@ f_{IS} = 1 kHz
- High degree of linearity .5% distortion typ.

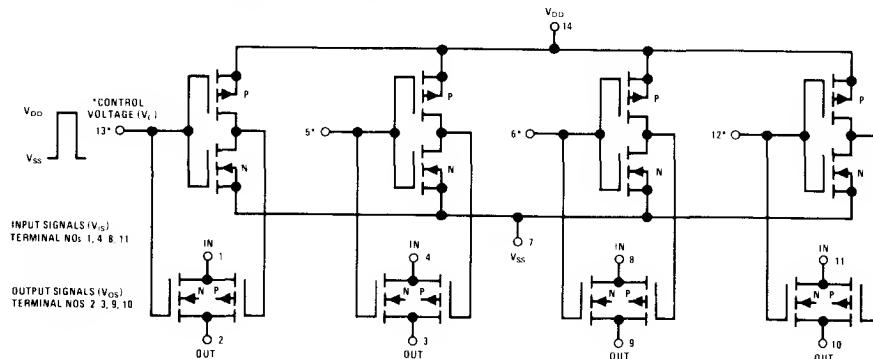
$$\begin{aligned} V_{IS} &= 5 \text{ V}_{PP} \\ V_{DD} - V_{SS} &= 10\text{V} \\ R_L &= 10 \text{k}\Omega \end{aligned}$$

- Extremely low leakage
- Transmits frequencies up to 10 MHz

Applications

- Analog signal switching/multiplexing
- Signal gating
- Squelch control
- Chopper
- Modulator
- Demodulator
- Commutating switch
- Digital signal switching/multiplexing
- CMOS logic implementation
- Analog to digital/digital to analog conversion
- Digital control of frequency, impedance, phase, and analog-signal gain

Schematic and Connection Diagrams

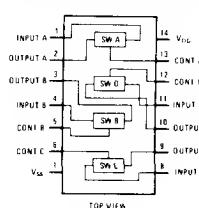


Note 1. All switch P channel substrates are internally connected to terminal No. 14
Note 2. All switch N channel substrates are internally connected to terminal No. 7

Signal-level range: V_{SS} ~ V_{IN} ~ V_{DD}

Normal operation: Control line biasing,
switch ON V_C "1" = V_{DD}, switch OFF V_C "0" = V_{SS}

Dual-In-Line and Flat Package



Order Number CD4016MD
See Package 14

Order Number CD4016MF
See Package 23

Order Number CD4016CJ or CD4016MJ
See Package 18

Order Number CD4016CN
See Package 21

Absolute Maximum Ratings

Voltage at Any Pin (Note 1)

 $V_{SS} = 0.3V$ to $V_{DD} + 15V$

Operating Temperature Range CD4016M

-55°C to +125°C

CD4016C

-40°C to +85°C

Storage Temperature Range

-65°C to +150°C

Package Dissipation

500 mW

Lead Temperature (Soldering, 10 sec)

300°C

Operating V_{DD} Range $V_{SS} + 3V$ to $V_{SS} + 15V$ **Electrical Characteristics**

CD4016M

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	LIMITS						UNITS	
			-55°C		25°C		125°C			
			MIN	Typ	MAX	MIN	Typ	MAX		
Quiescent Dissipation per Package		TERMINALS APPLIED								
All Switches "OFF"		V_{DD} 14 +10 V_{SS} 7 GND V_C 5 6 12 13 GND V_A 1 4, 8 11 $\leq +10$ V_{OA} 2 3 9 10 $\leq +10$			5	0.1	5		300 μW	
All Switches "ON"		TERMINALS APPLIED								
		V_{DD} 14 +10 V_{SS} 7 GND V_C 5 6 12 13 +10 $V_A = V_{DD}$ 1-4 8-11 $\leq +10$			5	0.1	5		300 μW	
Threshold Voltage N Channel	V_{THN}	$I_{DS} = 10 \mu A$ $V_{DD} = 5V, 10V$ or $15V$	1.7			1.5		1.3	V	
P Channel	V_{THP}	$I_{DS} = 10 \mu A$ $V_{DD} = 5V, 10V$ or $15V$	-1.7			-1.5		-1.3	V	
SIGNAL INPUTS (V_A) AND OUTPUTS (V_{OA})		$V_C = V_{DD}$ $V_{SS} = V_A$ +7.5V -7.5V +0.25V +5V -5V +5V -5V +0.25V +15V CV +0.25V +9.3V - +10V CV +0.25V +5.6V	120	360	200 400	300 600	400 960	500 2600	Ω	
"ON" Resistance	R_{ON}	$R_L = 10k\Omega$ +15V CV +0.25V +9.3V - +10V CV +0.25V +5.6V	120	360	200 400	300 600	400 960	500 2600	Ω	
Δ "ON" Resistance Between Any 2 of 4 Switches	ΔR_{ON}	+7.5V -7.5V -7.5V +5V -5V $\pm 5V$			10				Ω	
Sine Wave Response (Distortion)		$R_L = 10 k\Omega$ $f_s = 1 kHz$ $V_{DD} = 5V(p.p)$ $V_C = V_{SS}$ V_A +7.5V -7.5V +5V -5V -5V			0.4				%	
Input or Output Leakage-Switch "OFF" (Effective "OFF" Resistance)		+7.5V -7.5V -7.5V +5V -5V -5V			± 100				pA	
Input or Output Leakage-Switch "ON" (Effective "ON" Resistance)		+5V -5V -5V			± 100	125			nA	
Frequency Response-Switch "ON" (Sine Wave Input)		$V_C = V_{DD} = +5V$, $V_{SS} = -5V$ $R_L = 1 k\Omega$ $20 \log_{10} \frac{V_{o(A)}}{V_{n(A)}} = -3 dB$ $V_{DD} = 5V(p.p)$ $V_C = -5V$, $V_C = V_{SS} = -5V$ $20 \log_{10} \frac{V_{o(B)}}{V_{n(B)}} = -50 dB$			40				MHz	
Feedthrough Switch "OFF"		$V_C(A) = V_{DC} = +5V$ $R_L = 1 k\Omega$ $V_{n(A)} = 5V(p.p)$ $20 \log_{10} \frac{V_{o(A)}}{V_{n(A)}} = -50 dB$			1.25				MHz	
Crosstalk Between any 2 of the 4 switches (Frequency at -50 dB)		$R_L = 1 k\Omega$ $V_{n(A)} = 5V(p.p)$ $20 \log_{10} \frac{V_{o(B)}}{V_{n(A)}} = -50 dB$			0.9				MHz	
Capacitance Input Output Feedthrough	C_{IS} C_{OS} C_{IOS}	$V_{DD} = +5V$, $V_C = V_{SS} = -5V$ $V_C = V_{DD} = +10V$, $V_{SS} = GND$, $C_L = 15 pF$ $V_{DD} = 10V$ (square wave) $t_f = t_r = 20 ns$ (input signal)			4				pF	
Propagation Delay Signal Input to Signal Output	t_{PD}	$t_f = t_r = 20 ns$ (input signal)			10				ns	
CONTROL (V_C)		$V_A < V_{DD}$ $V_{DD} = V_{SS} = 15V, 10V, 5V$ $I_{IS} = 10 \mu A$ $V_{DD} = V_{SS} = 10V$ $V_C \leq V_{DD} - V_{SS}$	0.7	2.9	0.5	1.5	2.7	0.2	2.4	V
Switch Threshold Voltage	V_{THC}	$V_{DD} = V_{SS} = 10V$ $R_L = 10 k\Omega$ (square wave)								
Input Current	I_C	$t_f = t_r = 20 ns$ $V_A < 10V$, $C_L = 15 pF$				± 10			pA	
Average Input Capacitance Crosstalk - Control Input to Signal Output	C_C	$V_{DD} = V_{SS} = 10V$ $V_C = 10V$ (square wave)				5			pF	
Turn "ON" Propagation Delay	t_{PDG}	$t_f = t_r = 20 ns$ $V_A < 10V$, $C_L = 15 pF$ $V_{DD} = 10V$, $V_{SS} = GND$, $R_L = 1 k\Omega$ $V_C = 10V$ (square wave) $t_f = t_r = 20 ns$				20			ns	
Maximum Allowable Control Input Repetition Rate						10			MHz	

Note 1: The device should not be connected to circuits with the power on.

Note 2: $\pm 10 \times 10^{-3}$

Note 3: Symmetrical about 0V

Electrical Characteristics CD4016C

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	LIMITS						UNITS	
			-40°C			25°C				
			MIN	TYP	MAX	MIN	TYP	MAX		
Quiescent Dissipation per Package		VOLTS APPLIED								
All Switches 'OFF'	P _T	V _{DD} 14 / GND V _{SS} 5 6 12, 13 GND V _C 1 4 8, 11 < +10 V _o 2 3 9-10 < +10		5		0.1	5		80 μ W	
All Switches 'ON'		V _{DD} 14 +10 V _{SS} 7 GND V _C 5 6 12, 13 +10 V _o - V _{DS} 1-4, 8, 11 < +10		5		0.1	5		80 μ W	
Threshold Voltage N Channel	V _{THN}	I _{DS} = 10 μ A V _{DD} = 5V 10V or 15V	1.7			1.5		1.3	V	
P Channel	V _{THP}	I _{DS} = 10 μ A V _{DD} = 5V 10V or 15V	1.7			-1.5		1.3	V	
SIGNAL INPUTS (V _a) AND OUTPUTS (V _o)		V _C = V _{DD} V _{SS} V _a								
'ON' Resistance	R _{ON}	R _f 10k Ω	+7.5V / 7.5V +7.5V +15V 0V -0.25V 0.25V 9.3V +10V +5V -5V 5.6V	130 370 200 400 260 520 130 370 200 400 260 520 160 790 280 850 400 1080 150 610 250 660 340 840 150 610 250 660 340 840 350 1900 560 2000 750 2380					Ω	
'ON' Resistance Between Any 2 of 4 Switches	ΔR_{ON}		+7.5V / 7.5V +7.5V +15V 5V -5V	10 15					Ω	
Sine Wave Response (Distortion)		R _L = 10 k Ω f _s = 1 kHz	+5V -5V 5V (p-p) V _{DD} V _C = V _{SS} V _a	0.4					%	
Input or Output Leakage Switch 'OFF' (Effective 'OFF' Resistance)			+7.5V -7.5V 7.5V +5V -5V 5V	+100 +100 125 Note 1 Note 2 125					pA nA	
Frequency Response—Switch 'ON' (Sine Wave Input)		R _f 1 k Ω	V _C = V _{DD} +5V, V _{SS} 5V	40					MHz	
Feedthrough Switch 'OFF'		V _{DD} = 15V (p-p)	20 Log ₁₀ $\frac{V_o}{V_a}$ -3 dB 20 Log ₁₀ $\frac{V_o}{V_a}$ -50 dB		1.25				MHz	
Crosstalk Between any 2 of the 4 switches (Frequency at -50 dB)		R _L 1 k Ω	V _{C(A)} = V _{DD} +5V V _{C(B)} = V _{SS} -5V 5V (p-p)	0.9					MHz	
Capacitance Input Output Feedthrough	C _{IS} C _{OS} C _{OIS}	V _{DD} = +5V V _C V _{SS} -5V		4 4 0.2					pF	
Propagation Delay Signal Input to Signal Output	t _{PD}	V _C = V _{DD} +10V V _{SS} GND C _L = 15 pF V _o = 10V (square wave) t _o - t _i = 20 ns (input signal)			10				ns	
CONTROL (V _C)										
Switch Threshold Voltage	V _{THC}	V _{IS} = V _{DD} V _{DP} V _{SS} = 15V, 10V, 5V I _{IS} = 10 μ A			0.5	1.5 2.7			V	
Input Current	I _C	V _{DP} V _{SS} = 10V V _C = 10V V _C < V _{DD} - V _{SS}				± 10			pA	
Average Input Capacitance Crosstalk - Control Input to Signal Output	C _C	V _{DD} V _{SS} = 10V R _L = 10 k Ω V _C = 10V (square wave)				50			pF mV	
Turn 'ON' Propagation Delay	t _{on} C	t _o - t _i = 20 ns V _{IS} < 10V, C _L = 15 pF				20			ns	
Maximum Allowable Control Input Repetition Rate		V _{DD} = 10V V _{SS} GND R _L = 1 k Ω C _L = 15 pF V _C = 10V (square wave) t _o - t _i = 20 ns				10			MHz	

Note 1: The device should not be connected to circuits with the power on.

Note 2: $\pm 10 \times 10^{-3}$.

Note 3: Symmetrical about 0V.

Typical ON Resistance Characteristics

CHARACTERISTIC*	SUPPLY CONDITIONS		LOAD CONDITIONS					
			$R_L = 1 \text{ k}\Omega$		$R_L = 10 \text{ k}\Omega$		$R_L = 100 \text{ k}\Omega$	
	V_{DD} (V)	V_{SS} (V)	VALUE (Ω)	V_{DS} (V)	VALUE (Ω)	V_{DS} (V)	VALUE (Ω)	V_{DS} (V)
R_{ON}	+15	0	200	+15	200	+15	180	+15
$R_{ON}(\text{max})$	+15	0	300	+11	300	+9.3	320	+9.2
R_{ON}	+10	0	290	+10	250	+10	240	+10
$R_{ON}(\text{max})$	+10	0	500	+7.4	560	+5.6	610	+5.5
R_{ON}	-5	0	860	+5	470	+5	450	+5
$R_{ON}(\text{max})$	-5	0	600	0	580	0	800	0
R_{ON}	-5	0	17k	+4.2	7k	+2.9	33k	+2.7
R_{ON}	+7.5	+5	200	+7.5	200	+7.5	180	+7.5
$R_{ON}(\text{max})$	+7.5	+5	200	+0.25	280	+0.25	400	+0.25
R_{ON}	-5	5	310	5	250	5	240	5
$R_{ON}(\text{max})$	-5	5	600	+0.25	580	+0.25	760	+0.25
R_{LN}	+2.5	+2.5	720	+2.5	520	+2.5	520	+2.5
$R_{LN}(\text{max})$	+2.5	+2.5	232k	+0.25	300k	+0.25	870k	+0.25

*Variation from a perfect switch: $R_{ON} = 0\Omega$.